



60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on)	I _D T _C = +25°C
60V	$16m\Omega @ V_{GS} = 10V$	37.1A
607	$24m\Omega$ @ V _{GS} = 4.5V	30.3A

Description and Applications

This MOSFET has been designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Power managements
- DC-DC converters
- Motor controls

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH6016LPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

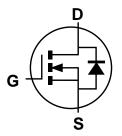
https://www.diodes.com/quality/product-definitions/

Mechanical Data

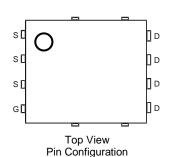
- Package: PowerDI®5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)







Internal Schematic



PowerDI5060-8/SWP (Type UX)





G S

sП D D D зΠ Пο GΠ

Top View

Pin Configuration

Top View

Bottom View

Internal Schematic

Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Number	Package	Qty.	Carrier	
DMTH6016LPSQ-13	PowerDI5060-8	2,500	Tape & Reel	
DMTH6016LPSQ-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel	

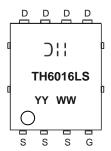
Notes:

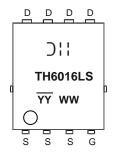
- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Document number: DS38518 Rev. 4 - 2



Marking Information





☐ Hanufacturer's Marking
TH6016LS = Product Type Marking Code
YYWW = Date Code Marking
YY or YY = Last Two Digits of Year (ex: 23 = 2023)
WW = Week Code (01 to 53)

Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V_{DSS}	60	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 6) $V_{GS} = 10V$ $T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$		l _D	37.1 26.2	Α	
Continuous Drain Current (Note 5) $V_{GS} = 10V$ Steady $T_A = +25^{\circ}C$ State $T_A = +100^{\circ}C$		lo	10.6 7.5	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	145	Α		
Maximum Continuous Body Diode Forward Current (Note 6)			Is	31	Α
Avalanche Current, L = 0.1mH			I _{AS}	15.3	Α
Avalanche Energy, L = 0.1mH			Eas	11.7	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25$ °C	PD	3	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{θJA}	49	°C/W
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$			37.5	W
Thermal Resistance, Junction to Case (Note 6)	Rejc	4	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +175	°C	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

^{6.} Thermal resistance from junction to soldering point (on the exposed drain pad).



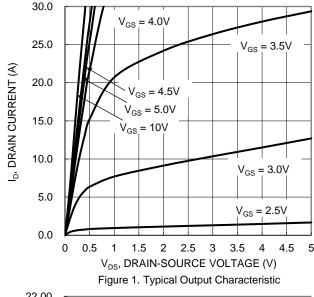
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	60		_	V	$V_{GS} = 0V, I_{D} = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μΑ	V _{DS} = 48V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(TH)	1	_	2.5	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance		_	12.4	16	0	V _G S = 10V, I _D = 20A	
Static Drain-Source On-Resistance	RDS(ON)	_	18.2	24	mΩ	V _{GS} = 4.5V, I _D = 18A	
Diode Forward Voltage	V_{SD}	_	0.7	1.2	V	$V_{GS} = 0V$, $I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 8)	•	•			•	•	
Input Capacitance	Ciss	_	864	_		V _{DS} = 30V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	_	282	_	pF		
Reverse Transfer Capacitance	Crss	_	27	_			
Gate Resistance	Rg	_	1.3	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	8.4	_			
Total Gate Charge (V _{GS} = 10V)	Qg	_	17	_		1/ 001/ 1 404	
Gate-Source Charge	Q _{gs}	_	3.1	_	nC	V _{DS} = 30V, I _D = 10A	
Gate-Drain Charge	Qgd	_	4.3	_			
Turn-On Delay Time	t _{D(ON)}	_	3.4	_			
Turn-On Rise Time	t _R	_	5.2	_		$V_{GS} = 10V, V_{DS} = 30V,$ $R_{G} = 6\Omega, I_{D} = 10A$	
Turn-Off Delay Time	tD(OFF)	_	13	_	ns		
Turn-Off Fall Time	tF	_	7	_			
Reverse Recovery Time	trr	_	22	_	ns	1 400 11/11 4000/	
Reverse Recovery Charge	Q _{RR}	_	11	_	nC	I _F = 10A, di/dt = 100A/μs	

7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing. Notes:







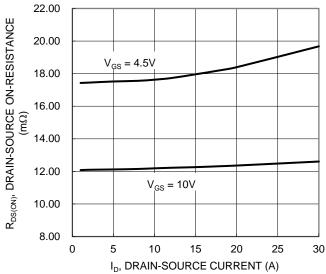


Figure 3. Typical On-Resistance vs Drain Current and Gate Voltage

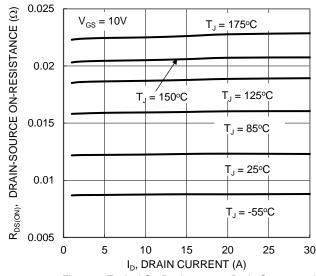
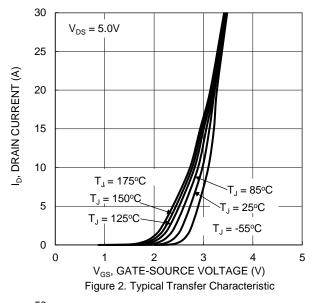


Figure 5. Typical On-Resistance vs Drain Current and Temperature



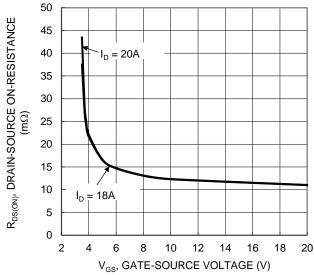


Figure 4. Typical Transfer Characteristic

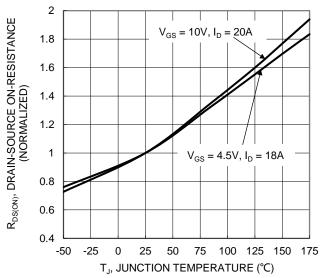
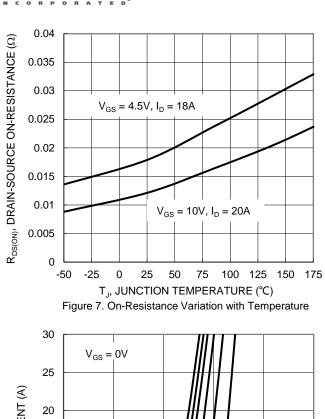
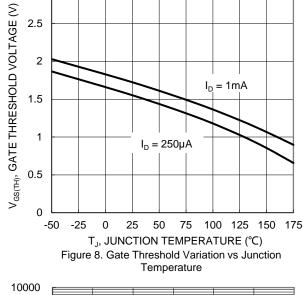


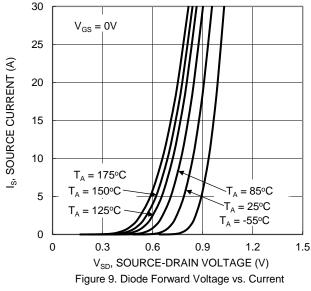
Figure 6. On-Resistance Variation with Temperature

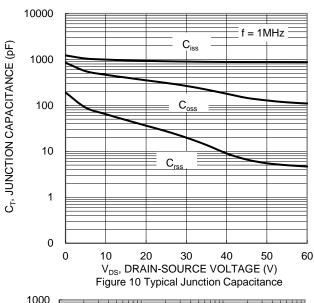


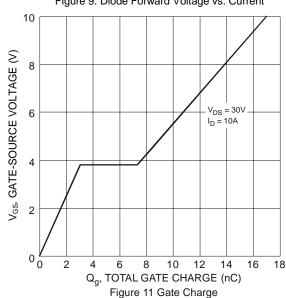


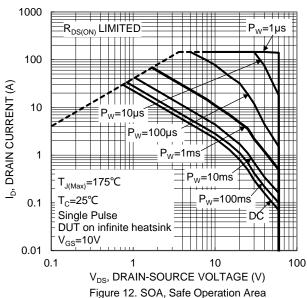


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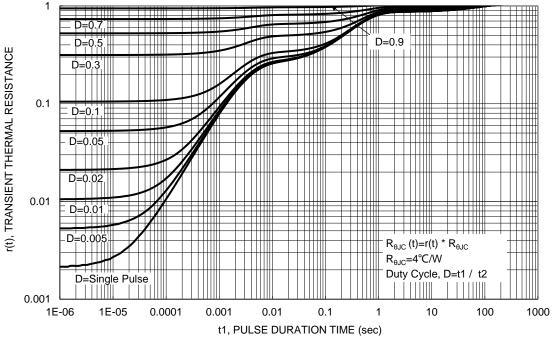


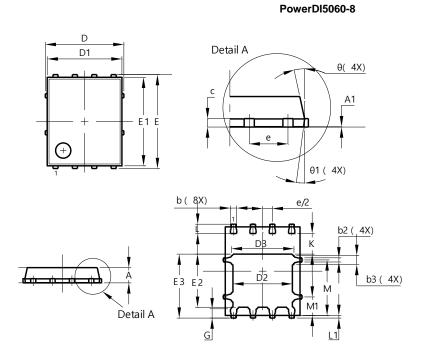
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

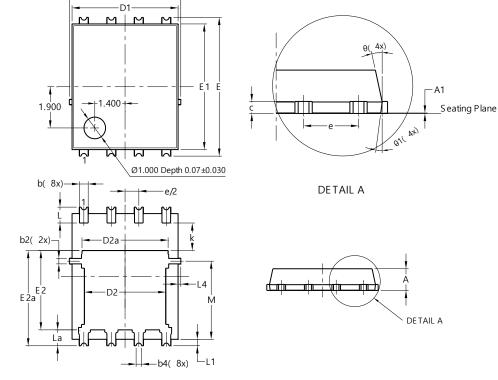
Site 1:



PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	Į.	5.15 BSC	,		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	(6.15 BSC	,		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC	,		
G	0.51	0.71	0.61		
K	0.51	-	1		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
M	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

Site 2:

PowerDI5060-8/SWP (Type UX)



Dim Min Max Typ A 0.90 1.10 1.00 A1 0 0.05 b 0.30 0.50 0.41 b2 0.20 0.35 0.25 b4 0.25REF - c 0.230 0.330 0.277 D 5.15 BSC D1 4.70 5.10 4.90 D2 3.56 3.96 3.76 D2a 3.78 4.18 3.98 E 6.40 BSC - E1 5.60 6.00 5.80 E2 3.46 3.86 3.66 E2a 4.195 4.595 4.395 e 1.27BSC L 0.635 0.835 0.735 La 0.635 0.835 0.735 La 0.635 0.835 0.735 L1 0.200 0.400 0.300 L1 <t< th=""><th colspan="5">PowerDI5060-8/SWP (Type UX)</th></t<>	PowerDI5060-8/SWP (Type UX)				
A1 0 0.05 b 0.30 0.50 0.41 b2 0.20 0.35 0.25 b4 0.25REF c 0.230 0.330 0.277 D 5.15 BSC D1 4.70 5.10 4.90 D2 3.56 3.96 3.76 D2a 3.78 4.18 3.98 E 6.40 BSC E1 5.60 6.00 5.80 E2 3.46 3.86 3.66 E2a 4.195 4.595 4.395 e 1.27BSC k 1.05 L 0.635 0.835 0.735 La 0.635 0.835 0.735 La 0.050 REF L4 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ 10° <	Dim	Min	Max	Тур	
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b2 0.20 0.35 0.25 b4 0.25REF c 0.230 0.330 0.277 D 5.15 BSC D1 4.70 5.10 4.90 D2 3.56 3.96 3.76 D2a 3.78 4.18 3.98 E 6.40 BSC E1 5.60 6.00 5.80 E2 3.46 3.86 3.66 E2a 4.195 4.595 4.395 e 1.27BSC k 1.05 L 0.635 0.835 0.735 La 0.635 0.835 0.735 L1 0.200 0.400 0.300 L1a 0.050REF L4 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ 10° 8° 7°	A 1	0	0.05		
b4 0.25REF c 0.230 0.330 0.277 D 5.15 BSC D1 4.70 5.10 4.90 D2 3.56 3.96 3.76 D2a 3.78 4.18 3.98 E 6.40 BSC E1 5.60 6.00 5.80 E2 3.46 3.86 3.66 E2a 4.195 4.595 4.395 e 1.27BSC k 1.05 L 0.635 0.835 0.735 La 0.635 0.835 0.735 La 0.050 0.400 0.300 L1 0.050 REF L4 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ 10° 8° 7°		0.30	0.50	0.41	
c 0.230 0.330 0.277 D 5.15 BSC D1 4.70 5.10 4.90 D2 3.56 3.96 3.76 D2a 3.78 4.18 3.98 E 6.40 BSC E1 5.60 6.00 5.80 E2 3.46 3.86 3.66 E2a 4.195 4.595 4.395 e 1.27BSC k 1.05	b2	0.20	0.35	0.25	
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D2a 3.78 4.18 3.98 E 6.40 BSC 6.00 5.80 E2 3.46 3.86 3.66 E2a 4.195 4.595 4.395 e 1.27BSC L 0.635 0.835 0.735 La 0.635 0.835 0.735 L1 0.200 0.400 0.300 L1 0.050REF L4 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7°		4.70	5.10		
E 6.40 BSC E1 5.60 6.00 5.80 E2 3.46 3.86 3.66 E2a 4.195 4.595 4.395 e 1.27BSC k 1.05 L 0.635 0.835 0.735 La 0.635 0.835 0.735 L1 0.200 0.400 0.300 L1 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7°	D2	3.56	3.96	3.76	
E1 5.60 6.00 5.80 E2 3.46 3.86 3.66 E2a 4.195 4.595 4.395 e 1.27BSC - k 1.05 L 0.635 0.835 0.735 La 0.635 0.835 0.735 L1 0.200 0.400 0.300 L1a 0.050REF L4 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7°		3.78	4.18	3.98	
E2 3.46 3.86 3.66 E2a 4.195 4.595 4.395 e 1.27BSC k 1.05 L 0.635 0.835 0.735 La 0.635 0.835 0.735 L1 0.200 0.400 0.300 L1a 0.050REF L4 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7°		6	.40 BS0	2	
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e 1.27BSC k 1.05 L 0.635 0.835 0.735 La 0.635 0.835 0.735 L1 0.200 0.400 0.300 L1a 0.050REF L4 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7°	E2	3.46	3.86	3.66	
k 1.05 L 0.635 0.835 0.735 La 0.635 0.835 0.735 L1 0.200 0.400 0.300 L1a 0.050REF L4 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7°	E2a	4.195	4.595	4.395	
L 0.635 0.835 0.735 La 0.635 0.835 0.735 L1 0.200 0.400 0.300 L1a 0.050REF L4 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7°	е	1	.27BSC		
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L1 0.200 0.400 0.300 L1a 0.050REF L4 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7°	_	0.635	0.835	0.735	
L1a 0.050REF L4 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7°			0.835		
L4 0.025 0.225 0.125 M 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7°	L1	0.200	0.400	0.300	
M 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7°	L1a				
θ 10° 12° 11° θ1 6° 8° 7°	L4	0.025	0.225	0.125	
θ1 6° 8° 7°			4.005		
	θ				
All Discounting to	01 6° 8° 7°				
All Dimensions in mm					

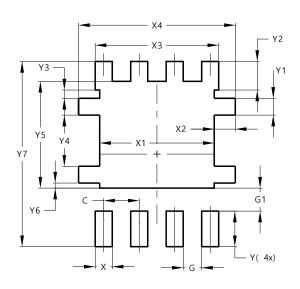


Suggested Pad Layout

 $\label{prop:package-outlines.html} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

Site 1:

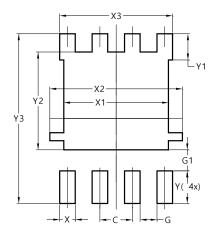
PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)



Dimensions	Value		
פווטופוופווט	(in mm)		
C	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	4.100		
X2	5.190		
Х3	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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